# CAT5115

# 32-Tap Digitally Programmable Potentiometer (DPP™)

DNDUCTOR, INC



# **FEATURES**

- 32-position linear taper potentiometer
- Low power CMOS technology
- Single supply operation: 2.5V 6V
- Increment up/down serial interface
- Resistance values: 10kΩ, 50kΩ and 100kΩ
- Available in PDIP, SOIC, TSSOP, MSOP and space saving 2 x 2.5mm TDFN packages

# **APPLICATIONS**

- Automated product calibration
- Remote control adjustments
- Offset, gain and zero control
- Tamper-proof calibrations
- Contrast, brightness and volume controls
- Motor controls and feedback systems
- Programmable analog functions

For Ordering Information details, see page 13.

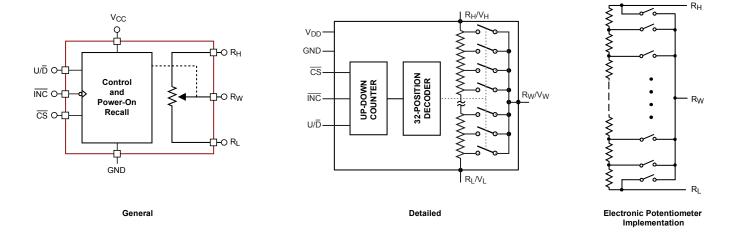
# DESCRIPTION

The CAT5115 is a single digitally programmable potentiometer (DPP<sup>™</sup>) designed as a electronic replacement for mechanical potentiometers and trim pots. Ideal for automated adjustments on high volume production lines, they are also well suited for applications where equipment requiring periodic adjustment is either difficult to access or located in a hazardous or remote environment.

The CAT5115 contains a 32-tap series resistor array connected between two terminals  $R_H$  and  $R_L$ . An up/down counter and decoder that are controlled by three input pins, determines which tap is connected to the wiper,  $R_W$ . The wiper is always set to the mid point, tap 15 at power up. The tap position is not stored in memory. Wiper-control of the CAT5115 is accomplished with three input control pins,  $\overline{CS}$ ,  $U/\overline{D}$ , and  $\overline{INC}$ . The  $\overline{INC}$  input increments the wiper in the direction which is determined by the logic state of the  $U/\overline{D}$  input. The  $\overline{CS}$  input is used to select the device.

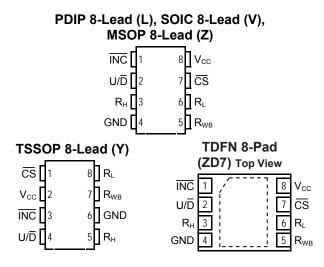
The digitally programmable potentiometer can be used as a three-terminal resistive divider or as a two-terminal variable resistor. DPPs bring variability and programmability to a wide variety of applications including control, parameter adjustments, and signal processing.

For a pin-compatible device that recalls a stored tap position on power-up refer to the CAT5114 data sheet.



# FUNCTIONAL DIAGRAM

# **PIN CONFIGURATION**



# **PIN FUNCTION**

### **INC**: Increment Control Input

The  $\overline{\text{INC}}$  input moves the wiper in the up or down direction determined by the condition of the U/ $\overline{D}$  input.

# U/D: Up/Down Control Input

The U/ $\overline{D}$  input controls the direction of the wiper movement. When in a high state and  $\overline{CS}$  is low, any high-to-low transition on INC will cause the wiper to move one increment toward the R<sub>H</sub> terminal. When in a low state and  $\overline{CS}$  is low, any high-to-low transition on INC will cause the wiper to move one increment towards the R<sub>L</sub> terminal.

# **R<sub>H</sub>:** High End Potentiometer Terminal

 $R_H$  is the high end terminal of the potentiometer. It is not required that this terminal be connected to a potential greater than the  $R_L$  terminal. Voltage applied to the  $R_H$  terminal cannot exceed the supply voltage,  $V_{CC}$  or go below ground, GND.

# $\mathbf{R}_{\mathbf{W}}$ : Wiper Potentiometer Terminal

 $R_W$  is the wiper terminal of the potentiometer. Its position on the resistor array is controlled by the control inputs,  $\overline{INC}$ , U/ $\overline{D}$  and  $\overline{CS}$ . Voltage applied to the  $R_W$  terminal cannot exceed the supply voltage,  $V_{CC}$  or go below ground, GND.

# RL: Low End Potentiometer Terminal

 $R_{\rm L}$  is the low end terminal of the potentiometer. It is not required that this terminal be connected to a potential less than the  $R_{\rm H}$  terminal. Voltage applied to the  $R_{\rm L}$  terminal cannot exceed the supply voltage,  $V_{\rm CC}$  or go below ground, GND.  $R_{\rm L}$  and  $R_{\rm H}$  are electrically interchangeable.

# **PIN DESCRIPTIONS**

Name	Function
ĪNC	Increment Control
U/D	Up/Down Control
R <sub>H</sub>	Potentiometer High Terminal
GND	Ground
Rw	Buffered Wiper Terminal
RL	Potentiometer Low Terminal
ĈŜ	Chip Select
$V_{CC}$	Supply Voltage

# **CS**: Chip Select

The chip select input is used to activate the control input of the CAT5115 and is active low. When in a high state, activity on the  $\overline{INC}$  and  $U/\overline{D}$  inputs will not affect or change the position of the wiper.

# **DEVICE OPERATION**

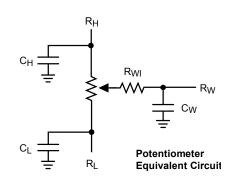
The CAT5115 operates like a digitally controlled potentiometer with  $R_H$  and  $R_L$  equivalent to the high and low terminals and  $R_W$  equivalent to the mechanical potentiometer's wiper. There are 32 available tap positions including the resistor end points,  $R_H$  and  $R_L$ . There are 31 resistor elements connected in series between the  $R_H$  and  $R_L$  terminals. The wiper terminal is connected to one of the 32 taps and controlled by three inputs,  $\overline{INC}$ ,  $U/\overline{D}$  and  $\overline{CS}$ . These inputs control a five-bit up/down counter whose output is decoded to select the wiper position.

With  $\overline{CS}$  set LOW the CAT5115 is selected and will respond to the U/D and  $\overline{INC}$  inputs. HIGH to LOW transitions on  $\overline{INC}$  will increment or decrement the wiper (depending on the state of the U/D input and five-bit counter). The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. When the CAT5115 is powered-down, the wiper position is reset. When power is restored, the counter is set to the mid point, tap 15.



#### **OPERATION MODES**

INC	ĊS	U/D	Operation
High to Low	Low	High	Wiper toward H
High to Low	Low	Low	Wiper toward L
High	Low to High	Х	Store Wiper Position
Low	Low to High	Х	No Store, Return to Standby
Х	High	Х	Standby



# ABSOLUTE MAXIMUM RATINGS (1)

Parameters	Ratings	Units
Supply Voltage		
V <sub>CC</sub> to GND	-0.5 to +7V	V
Inputs		
CS to GND	-0.5 to V <sub>CC</sub> +0.5	V
INC to GND	-0.5 to V <sub>CC</sub> +0.5	V
U/D to GND	-0.5 to V <sub>CC</sub> +0.5	V
H to GND	-0.5 to V <sub>CC</sub> +0.5	V
L to GND	-0.5 to V <sub>CC</sub> +0.5	V
W to GND	-0.5 to V <sub>CC</sub> +0.5	V

Parameters	Ratings	Units
Operating Ambient Temperature		
Industrial ('l' suffix)	-40 to +85	°C
Junction Temperature	+150	°C
Storage Temperature	-65 to 150	°C
Lead Soldering (10s max)	+300	°C

### **RELIABILITY CHARACTERISTICS**

Symbol	Parameter	Test Method	Min	Тур	Max	Units
V <sub>ZAP</sub> <sup>(2)</sup>	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000			V
I <sub>LTH</sub> <sup>(2) (3)</sup>	Latch-Up	JEDEC Standard 17	100			mA
T <sub>DR</sub>	Data Retention	MIL-STD-883, Test Method 1008	100			Years
N <sub>END</sub>	Endurance	MIL-STD-883, Test Method 1003	1,000,000			Stores

#### **DC ELECTRICAL CHARACTERISTICS**

Vcc = +2.5V to +6V unless otherwise specified

### **Power Supply**

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>cc</sub>	Operating Voltage Range		2.5	-	6	V
I <sub>CC1</sub> Supply Current (Increment	Supply Current (Increment)	$V_{CC} = 6V, f = 1MHz, I_W = 0$	-	-	100	μA
	Supply Current (increment)	$V_{CC} = 6V, f = 250 \text{kHz}, I_W = 0$	-	-	50	μA
I <sub>SB1</sub> <sup>(3)</sup>	Supply Current (Standby)	$\overline{CS} = V_{CC} - 0.3V$ U/D, INC = V <sub>CC</sub> - 0.3V or GND	_	0.01	1	μA

#### Notes:

(1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.

(2) This parameter is tested initially and after a design or process change that affects the parameter.

(3) Latch-up protection is provided for stresses up to 100mA on address and data pins from -1V to  $V_{CC}$  + 1V.

(4)  $I_W$  = source or sink.

(5) These parameters are periodically sampled and are not 100% tested.

# Logic Inputs

Symbol	Parameter	Conditions	Min	Тур	Max	Units
I <sub>IH</sub>	Input Leakage Current	$V_{IN} = V_{CC}$	-	_	10	μA
I <sub>IL</sub>	Input Leakage Current	$V_{IN} = 0V$	_	-	-10	μA
V <sub>IH1</sub>	TTL High Level Input Voltage		2	-	V <sub>CC</sub>	V
V <sub>IL1</sub>	TTL Low Level Input Voltage	$4.5V \le V_{CC} \le 5.5V$	0	-	0.8	V
V <sub>IH2</sub>	CMOS High Level Input Voltage	2.5V ≤ V <sub>CC</sub> ≤ 6V	V <sub>CC</sub> x 0.7	-	V <sub>CC</sub> + 0.3	V
V <sub>IL2</sub>	CMOS Low Level Input Voltage	$2.5V \leq V_{CC} \leq 6V$	-0.3	-	V <sub>CC</sub> x 0.2	V

# Potentiometer Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
		-10 Device		10		
R <sub>POT</sub>	Potentiometer Resistance	-50 Device		50		kΩ
		-00 Device		100		
	Pot. Resistance Tolerance				±20	%
V <sub>RH</sub>	Voltage on R <sub>H</sub> pin		0		V <sub>CC</sub>	V
V <sub>RL</sub>	Voltage on R <sub>L</sub> pin		0		V <sub>CC</sub>	V
	Resolution			3.2		%
INL	Integral Linearity Error	I <sub>W</sub> ≤ 2µA		0.5	1	LSB
DNL	Differential Linearity Error	I <sub>W</sub> ≤ 2µA		0.25	0.5	LSB
Р	Winer Desistance	$V_{\rm CC}$ = 5V, $I_{\rm W}$ = 1mA		70	200	Ω
R <sub>WI</sub>	Wiper Resistance	V <sub>CC</sub> = 2.5V, I <sub>W</sub> = 1mA		150	400	Ω
I <sub>W</sub>	Wiper Current	(1)			1	mA
TC <sub>RPOT</sub>	TC of Pot Resistance			±50	±300	ppm/ºC
TC <sub>RATIO</sub>	Ratiometric TC				20	ppm/°C
V <sub>N</sub>	Noise	100kHz / 1kHz		8/24		nV/√Hz
$C_H/C_L/C_W$	Potentiometer Capacitances			8/8/25		pF
fc	Frequency Response	Passive Attenuator, $10k\Omega$		1.7		MHz



### AC CONDITIONS OF TEST

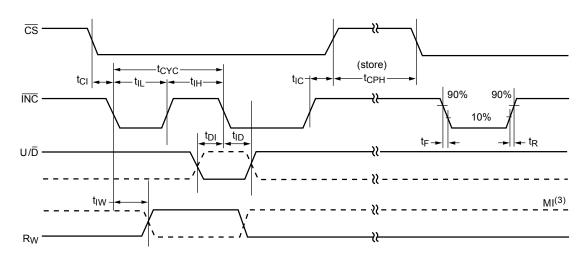
V <sub>CC</sub> Range	$2.5V \le V_{CC} \le 6.0V$
Input Pulse Levels	$0.2V_{CC}$ to $0.7V_{CC}$
Input Rise and Fall Times	10ns
Input Reference Levels	0.5V <sub>CC</sub>

# AC OPERATING CHARACTERISTICS

 $V_{CC}$  = +2.5V to +6.0V,  $V_{H}$  =  $V_{CC}$ ,  $V_{L}$  = 0V, unless otherwise specified

Symbol	Parameter	Min	Typ <sup>(1)</sup>	Max	Units
t <sub>CI</sub>	CS to INC Setup	100	_	_	ns
t <sub>DI</sub>	U/D to INC Setup	50	-	-	ns
t <sub>ID</sub>	U/D to INC Hold	100	-	-	ns
t <sub>IL</sub>	INC LOW Period	250	_	_	ns
t <sub>IH</sub>	INC HIGH Period	250	_	_	ns
t <sub>IC</sub>	INC Inactive to CS Inactive	1	-	_	μs
t <sub>CPH</sub>	CS Deselect Time	100	_	_	ns
t <sub>IVV</sub>	INC to V <sub>OUT</sub> Change	_	1	5	μs
t <sub>CYC</sub>	INC Cycle Time	1	_	_	μs
$t_R, t_F^{(2)}$	INC Input Rise and Fall Time	_	_	500	μs
t <sub>PU</sub> <sup>(2)</sup>	Power-up to Wiper Stable	_	_	1	ms

### A.C. TIMING

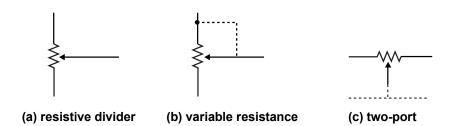


- (1) Typical values are for  $T_A = 25^{\circ}C$  and nominal supply voltage.
- (2) This parameter is periodically sampled and not 100% tested.
- (3) MI in the A.C. Timing diagram refers to the minimum incremental change in the W output due to a change in the wiper position.

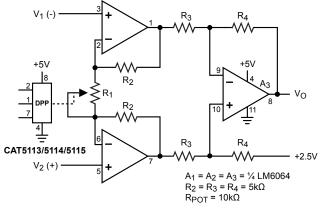


# **APPLICATIONS INFORMATION**

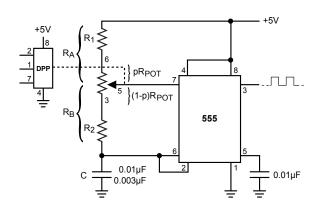
### POTENTIOMETER CONFIGURATION



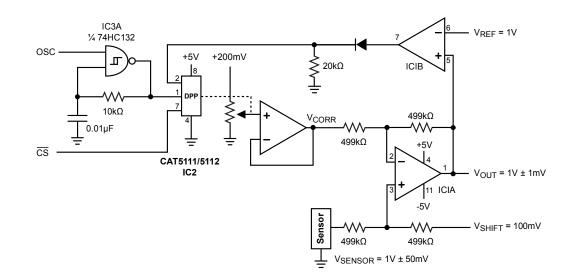
### **APPLICATIONS**



Programmable Instrumentation Amplifier

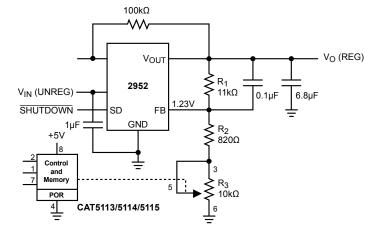


#### Programmable Sq. Wave Oscillator (555)

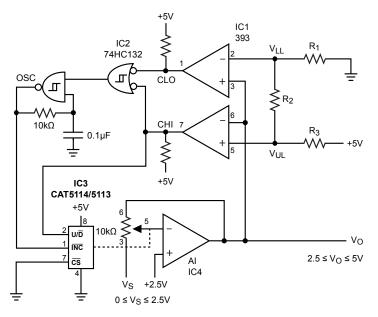


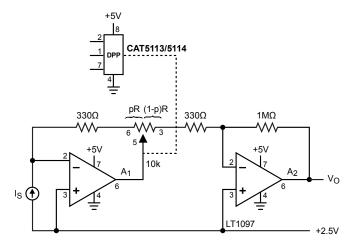
**Sensor Auto Referencing Circuit** 



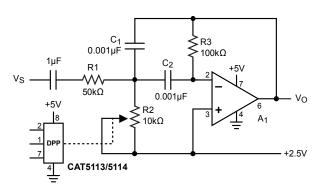


# Programmable Voltage Regulator



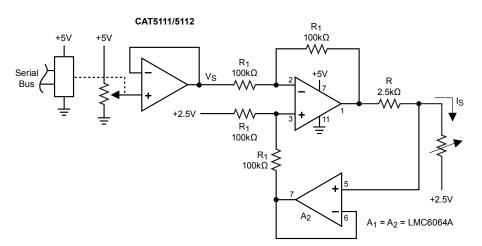


Programmable I to V Converter



### Automatic Gain Control

### **Programmable Bandpass Filter**

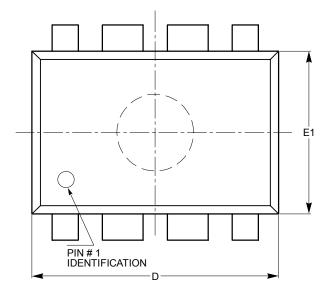


### Programmable Current Source/Sink



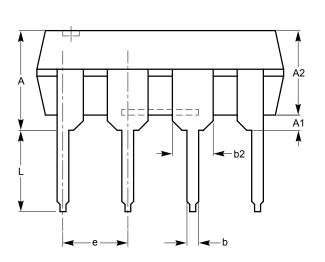
# PACKAGE OUTLINE DRAWINGS

PDIP 8-Lead 300mils (L) (1)(2)

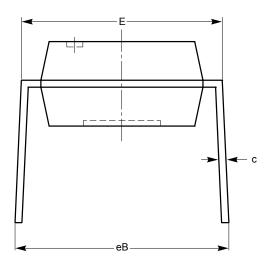


SYMBOL	MIN	NOM	MAX
A			5.33
A1	0.38		
A2	2.92	3.30	4.95
b	0.36	0.46	0.56
b2	1.14	1.52	1.78
с	0.20	0.25	0.36
D	9.02	9.27	10.16
E	7.62	7.87	8.25
е		2.54 BSC	
E1	6.10	6.35	7.11
eB	7.87		10.92
L	2.92	3.30	3.80

TOP VIEW



SIDE VIEW



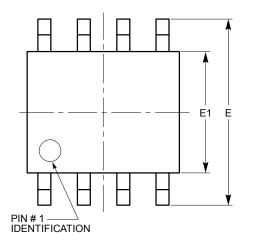
END VIEW

For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC standard MS-001.



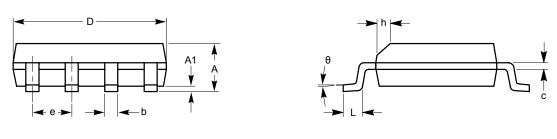
# SOIC 8-Lead 150mils (V) $^{\rm (1)(2)}$



SYMBOL MIN NOM MAX A 1.35 1.75 0.10 0.25 A1 b 0.33 0.51 0.25 0.19 С D 5.00 4.80 Е 5.80 6.20 3.80 4.00 E1 1.27 BSC е h 0.25 0.50 0.40 1.27 L 0° θ 8°

TOP VIEW

SIDE VIEW



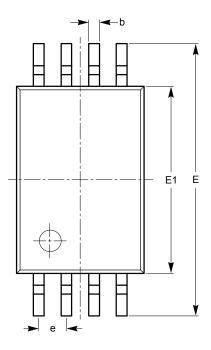
END VIEW

For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MS-012.

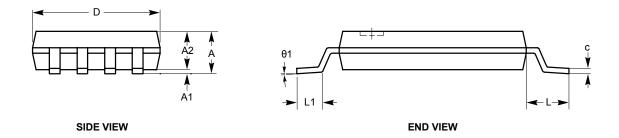


# TSSOP 8-Lead 4.4mm (Y) (1)(2)



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80	0.90	1.05
b	0.19		0.30
с	0.09		0.20
D	2.90	3.00	3.10
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L		1.00 REF	
L1	0.50	0.60	0.75
θ1	0°		8°

TOP VIEW

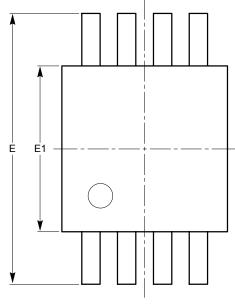


For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MO-153.

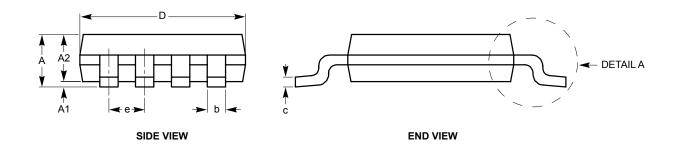


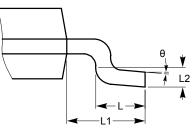
# MSOP 8-Lead 3.0 x 3.0mm (Z) $^{(1)(2)}$



TOP VIEW

SYMBOL	MIN	NOM	MAX
Α			1.10
A1	0.05	0.10	0.15
A2	0.75	0.85	0.95
b	0.22		0.38
с	0.13		0.23
D	2.90	3.00	3.10
E	4.80	4.90	5.00
E1	2.90	3.00	3.10
е	0.65 BSC		
L	0.40	0.60	0.80
L1	0.95 REF		
L2	0.25 BSC		
θ	0°		6°





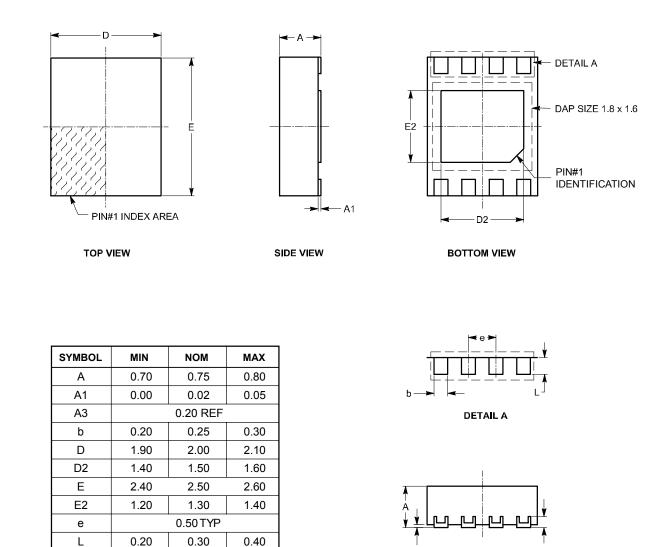
DETAIL A

For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MO-187.



# TDFN 8-Pad 2 x 2.5mm (ZD7) (1)(2)



For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

A1

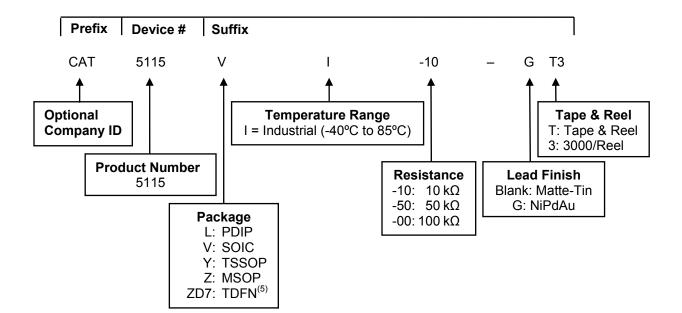
A3

FRONT VIEW

- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC standard MO-229.



# **EXAMPLE OF ORDERING INFORMATION**



ORDERING PART NUMBER
CAT5115LI-10-G
CAT5115LI-50-G
CAT5115LI-00-G
CAT5115VI-10-G
CAT5115VI-50-G
CAT5115VI-00-G
CAT5115YI-10-G
CAT5115YI-50-G
CAT5115YI-00-G
CAT5115ZI-10-G
CAT5115ZI-50-G
CAT5115ZI-00-G
CAT5115ZD7I-10 <sup>(6)</sup>
CAT5115ZD7I-50 <sup>(6)</sup>
CAT5115ZD7I-00 <sup>(6)</sup>

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free).
- (2) The standard lead finish is NiPdAu.
- (3) This device used in the above example is a CAT5115VI-10-GT3 (SOIC, Industrial Temperature, 10kΩ, NiPdAu, Tape & Reel).
- (4) For additional package and temperature options, please contact your nearest Catalyst Semiconductor Sales office.
- (5) TDFN is not available in NiPdAu (-G) version.
- (6) Contact factory for package availability.

# **REVISION HISTORY**

Date	Rev.	Reason	
09/25/2003	В	Changed designation to Preliminary. Updated Description. Updated Potentiometer Parameters table.	
03/10/2004	С	Updated Potentiometer Parameters table.	
03/29/2004	D	Changed Green Package marking for SOIC from W to V	
04/12/2004	Е	Updated Tape and Reel specs in Ordering Information	
08/31/2004	F	Deleted ICC2 from DC Characteristics table Updated AC Operating Characteristics table Updated A.C. Timing diagram.	
07/06/2007	G	Update Absolute Maximum Ratings table Update DC Electrical Characteristics tables Update AC Conditions of Test table Update all Package Outline Drawings Update Example of Ordering Information Update Ordering Part Number	
02/04/2008	Н	Update Functional Diagram Update Package Outline Drawings	

#### Copyrights, Trademarks and Patents

© Catalyst Semiconductor, Inc.

Trademarks and registered trademarks of Catalyst Semiconductor include each of the following: Adaptive Analog<sup>™</sup>, Beyond Memory<sup>™</sup>, DPP<sup>™</sup>, EZDim<sup>™</sup>, LDD<sup>™</sup>, MiniPot<sup>™</sup>, Quad-Mode<sup>™</sup> and Quantum Charge Programmable<sup>™</sup>

Catalyst Semiconductor has been issued U.S. and foreign patents and has patent applications pending that protect its products.

CATALYST SEMICONDUCTOR MAKES NO WARRANTY, REPRESENTATION OR GUARANTEE, EXPRESS OR IMPLIED, REGARDING THE SUITABILITY OF ITS PRODUCTS FOR ANY PARTICULAR PURPOSE, NOR THAT THE USE OF ITS PRODUCTS WILL NOT INFRINGE ITS INTELLECTUAL PROPERTY RIGHTS OR THE RIGHTS OF THIRD PARTIES WITH RESPECT TO ANY PARTICULAR USE OR APPLICATION AND SPECIFICALLY DISCLAIMS ANY AND ALL LIABILITY ARISING OUT OF ANY SUCH USE OR APPLICATION, INCLUDING BUT NOT LIMITED TO, CONSEQUENTIAL OR INCIDENTAL DAMAGES.

Catalyst Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Catalyst Semiconductor product could create a situation where personal injury or death may occur.

Catalyst Semiconductor reserves the right to make changes to or discontinue any product or service described herein without notice. Products with data sheets labeled "Advance Information" or "Preliminary" and other products described herein may not be in production or offered for sale.

Catalyst Semiconductor advises customers to obtain the current version of the relevant product information before placing orders. Circuit diagrams illustrate typical semiconductor applications and may not be complete.



Catalyst Semiconductor, Inc. Corporate Headquarters 2975 Stender Way Santa Clara, CA 95054 Phone: 408.542.1000 Fax: 408.542.1200 www.catsemi.com

Document No: MD-2117 Revision: H Issue date: 02/04/08